



**THE DATASHEET OF
LT1990AHS8#PBF**



±250V Input Range G = 1, 10, Micropower, Difference Amplifier

FEATURES

- Pin Selectable Gain of 1 or 10
- High Common Mode Voltage Range:
 85V Window ($V_S = 5V, 0V$)
 $\pm 250V$ ($V_S = \pm 15V$)
- Common Mode Rejection Ratio: 70dB Min
- Input Protection to $\pm 350V$
- Gain Error: 0.28% Max
- PSRR: 82dB Min
- High Input Impedance: $2M\Omega$ Differential,
 $500k\Omega$ Common Mode
- Micropower: $120\mu A$ Max Supply Current
- Wide Supply Range: 2.7V to 36V
- -3dB Bandwidth: 100kHz
- Rail-to-Rail Output
- 8-Pin SO Package

APPLICATIONS

- Battery Cell Voltage Monitoring
- High Voltage Current Sensing
- Signal Acquisition in Noisy Environments
- Input Protection
- Fault Protected Front Ends
- Level Sensing
- Isolation

DESCRIPTION

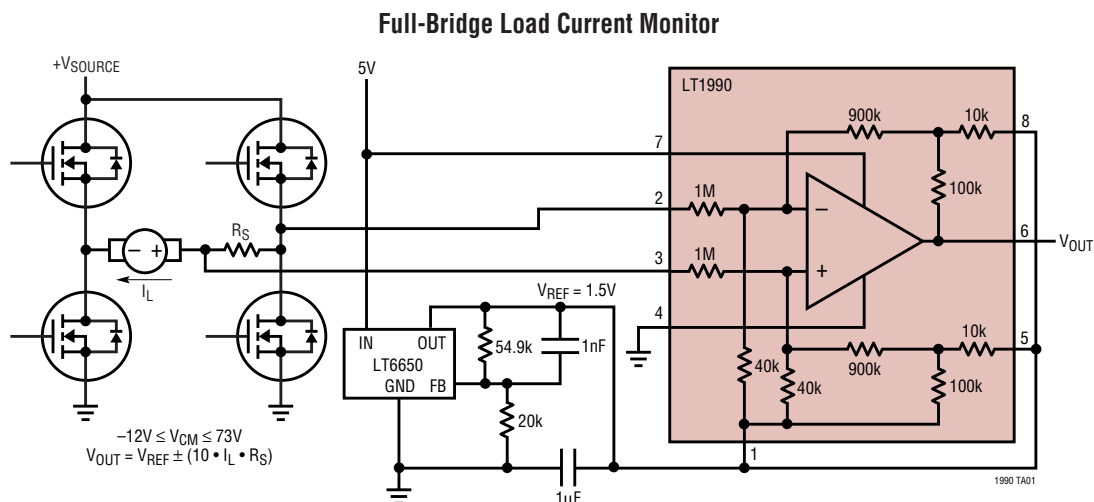
The LT[®]1990 is a micropower precision difference amplifier with a very high common mode input voltage range. It has pin selectable gains of 1 or 10. The LT1990 operates over a $\pm 250V$ common mode voltage range on a $\pm 15V$ supply. The inputs are fault protected from common mode voltage transients up to $\pm 350V$ and differential voltages up to $\pm 500V$. The LT1990 is ideally suited for both high side and low side current or voltage monitoring.

On a single 5V supply, the LT1990 has an adjustable 85V input range, 70dB min CMRR and draws less than $120\mu A$ supply current. The rail-to-rail output maximizes the dynamic range, especially important for single supplies as low as 2.7V.

The LT1990 is specified for single 3V, 5V and $\pm 15V$ supplies over both commercial and industrial temperature ranges. The LT1990 is available in the 8-pin SO package.

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TYPICAL APPLICATION

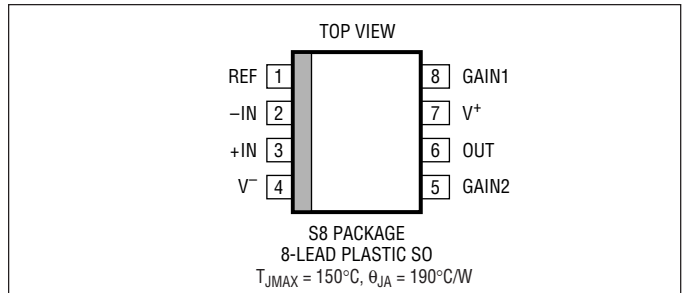


ABSOLUTE MAXIMUM RATINGS

(Notes 1, 2)

Total Supply Voltage (V^+ to V^-)	36V
Input Voltage Range	
Continuous	$\pm 250V$
Transient (0.1s)	$\pm 350V$
Differential	$\pm 500V$
Output Short-Circuit Duration (Note 3)	Indefinite
Operating Temperature Range (Note 4)	
LT1990C	$-40^\circ C$ to $85^\circ C$
LT1990I	$-40^\circ C$ to $85^\circ C$
LT1990H	$-40^\circ C$ to $125^\circ C$
Specified Temperature Range (Note 5)	
LT1990C	$-40^\circ C$ to $85^\circ C$
LT1990I	$-40^\circ C$ to $85^\circ C$
LT1990H	$-40^\circ C$ to $125^\circ C$
Junction Temperature	$150^\circ C$
Storage Temperature Range	$-65^\circ C$ to $150^\circ C$
Lead Temperature (Soldering, 10 sec.)	$300^\circ C$

PACKAGE/ORDER INFORMATION



ORDER PART NUMBER	S8 PART MARKING
LT1990CS8	1990
LT1990IS8	1990I
LT1990HS8	1990H
LT1990ACS8	1990A
LT1990AIS8	1990AI
LT1990AHS8	1990AH

Order Options Tape and Reel: Add #TR
 Lead Free: Add #PBF Lead Free Tape and Reel: Add #TRPBF
 Lead Free Part Marking: <http://www.linear.com/leadfree/>

Consult LTC Marketing for parts specified with wider operating temperature ranges.

3V/5V ELECTRICAL CHARACTERISTICS

$V_S = 3V, 0V; V_S = 5V, 0V; R_L = 10k, V_{CM} = V_{REF} = \text{half supply}, G = 1, 10, T_A = 25^\circ C$, unless otherwise noted. (Note 6)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
G	Gain	Pins 5 and 8 = Open Pins 5 and 8 = V_{REF}		1 10		
ΔG	Gain Error	$V_{OUT} = 0.5V$ to $(+V_S) - 0.75V$ LT1990, $G = 1$ LT1990A, $G = 1$ $G = 10, V_S = 5V, 0V$		0.4 0.07 0.2	0.6 0.28 0.8	% % %
GNL	Gain Nonlinearity	$V_S = 5V, 0V; V_{OUT} = 0.5V$ to $4.25V$ $G = 1$ $G = 10$		0.001 0.01	0.005	% %
V_{CM}	Input Voltage Range	Guaranteed by CMRR $V_S = 3V, 0V; V_{REF} = 1.25V$ $V_S = 5V, 0V; V_{REF} = 1.25V$ $V_S = 5V, 0V; V_{REF} = 2.5V$	-5 -5 -38		25 80 47	V V V
CMRR	Common Mode Rejection Ratio RTI (Referred to Input)	$V_S = 3V, 0V$ (Note 7) $V_{CM} = -5V$ to $25V, V_{REF} = 1.25V$ LT1990 LT1990A	60 70	68 75		dB dB
		$V_S = 5V, 0V$ $V_{CM} = -5V$ to $80V, V_{REF} = 1.25V$ LT1990 LT1990A	60 70	68 75		dB dB
		$V_S = 5V, 0V$ (Note 7) $V_{CM} = -38V$ to $47V, V_{REF} = 2.5V$ LT1990 LT1990A	60 70	68 75		dB dB

3V/5V ELECTRICAL CHARACTERISTICS

$V_S = 3V, 0V; V_S = 5V, 0V; R_L = 10k, V_{CM} = V_{REF} = \text{half supply}, G = 1, 10, T_A = 25^\circ C$, unless otherwise noted. (Note 6)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Offset Voltage, RTI	$G = 1, 10$		0.8	3	mV
e_n	Input Noise Voltage, RTI	$f_0 = 0.1\text{Hz to }10\text{Hz}$		22		μV_{P-P}
	Noise Voltage Density, RTI	$f_0 = 1\text{kHz}$		1		$\mu V/\sqrt{\text{Hz}}$
R_{IN}	Input Resistance	Differential Common Mode		2 0.5		$M\Omega$ $M\Omega$
PSRR	Power Supply Rejection Ratio, RTI	$V_S = 2.7V \text{ to } 12.7V, V_{CM} = V_{REF} = 1.25V$	80	92		dB
	Minimum Supply Voltage	Guaranteed by PSRR		2.4	2.7	V
I_S	Supply Current	(Note 8)		105	120	μA
V_{OL}	Output Voltage Swing LOW	$-IN = V^+, +IN = \text{Half Supply (Note 8)}$		30	50	mV
V_{OH}	Output Voltage Swing HIGH	$-IN = 0V, +IN = \text{Half Supply}$ $V_S = 3V, 0V, \text{Below } V^+$ $V_S = 5V, 0V, \text{Below } V^+$		100 120	150 175	mV mV
I_{SC}	Output Short-Circuit Current	Short to GND (Note 9) Short to V^+ (Note 9)	4 13	8 20		mA mA
BW	Bandwidth (-3dB)	$G = 1$ $G = 10$		100 6.5		kHz kHz
SR	Slew Rate	$G = 1, V_S = 5V, 0V, V_{OUT} = 0.5V \text{ to } 4.5V$		0.5		$V/\mu s$
	Settling Time to 0.01%	4V Step, $G = 1, V_S = 5V, 0V$		45		μs
AV_{REF}	Reference Gain to Output	$G = 1$ $G = 10$		1 ± 0.0007 1 ± 0.007		

The ● denotes the specifications which apply over the temperature range of $0^\circ C \leq T_A \leq 70^\circ C$. $V_S = 3V, 0V; V_S = 5V, 0V; R_L = 10k, V_{CM} = V_{REF} = \text{half supply}, G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990C/LT1990I			UNITS
			MIN	TYP	MAX	
ΔG	Gain Error	$V_{OUT} = 0.5V \text{ to } (+V_S) - 0.75V$ LT1990, $G = 1$ LT1990A, $G = 1$ $G = 10$	● ● ●		0.65 0.33 0.90	% % %
G/T	Gain vs Temperature	$G = 1$ (Note 10) $G = 10$ (Note 10)	● ●	2 7	10 20	ppm/ $^\circ C$ ppm/ $^\circ C$
V_{CM}	Input Voltage Range	Guaranteed by CMRR $V_S = 3V, 0V, V_{REF} = 1.25V$ $V_S = 5V, 0V, V_{REF} = 1.25V$ $V_S = 5V, 0V, V_{REF} = 2.5V$	● ● ●	-5 -5 -37	25 80 48	V V V
CMRR	Common Mode Rejection Ratio, RTI	$V_S = 3V, 0V$ (Note 7) $V_{CM} = -5V \text{ to } 25V, V_{REF} = 1.25V$ LT1990 LT1990A	● ●	58 68		dB dB
		$V_S = 5V, 0V$ $V_{CM} = -5V \text{ to } 80V, V_{REF} = 1.25V$ LT1990 LT1990A	● ●	58 68		dB dB
		$V_S = 5V, 0V$ (Note 7) $V_{CM} = -38V \text{ to } 47V, V_{REF} = 2.5V$ LT1990 LT1990A	● ●	58 68		dB dB

3V/5V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range of $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$. $V_S = 3\text{V}, 0\text{V}$; $V_S = 5\text{V}, 0\text{V}$; $R_L = 10\text{k}$, $V_{\text{CM}} = V_{\text{REF}} = \text{half supply}$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990C/LT1990I			UNITS
			MIN	TYP	MAX	
V_{OS}	Input Offset Voltage, RTI	$V_S = 3\text{V}, 0\text{V}$ $G = 1, 10$	●		4.1	mV
		$V_S = 5\text{V}, 0\text{V}$ $G = 1, 10$	●		4.1	mV
$V_{\text{OS/T}}$	Input Offset Voltage Drift, RTI	(Note 10)	●	5	22	$\mu\text{V}/^{\circ}\text{C}$
V_{OSH}	Input Offset Voltage Hysteresis, RTI	(Note 11)	●	230		μV
PSRR	Power Supply Rejection Ratio, RTI	$V_S = 2.7\text{V}$ to 12.7V $V_{\text{CM}} = V_{\text{REF}} = 1.25\text{V}$ $G = 1, 10$	●	78		dB
		Minimum Supply Voltage	Guaranteed by PSRR	●		2.7
I_S	Supply Current	(Note 8)	●		150	μA
V_{OL}	Output Voltage Swing LOW	$-IN = V^+$, $+IN = \text{Half Supply}$ (Note 8)	●		60	mV
V_{OH}	Output Voltage Swing HIGH	$-IN = 0\text{V}$, $+IN = \text{Half Supply}$ $V_S = 3\text{V}, 0\text{V}$, Below V^+	●		180	mV
		$V_S = 5\text{V}, 0\text{V}$, Below V^+	●		205	mV
I_{SC}	Output Short-Circuit Current	Short to GND (Note 9)	●	3		mA
		Short to V^+ (Note 9)	●	11		mA

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$. $V_S = 3\text{V}, 0\text{V}$; $V_S = 5\text{V}, 0\text{V}$; $R_L = 10\text{k}$, $V_{\text{CM}} = V_{\text{REF}} = \text{half supply}$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990C/LT1990I			UNITS
			MIN	TYP	MAX	
ΔG	Gain Error	$V_{\text{OUT}} = 0.5\text{V}$ to $(+V_S) - 0.75\text{V}$ LT1990, $G = 1$	●		0.67	%
		LT1990A, $G = 1$	●		0.35	%
		$G = 10$	●		0.95	%
G/T	Gain vs Temperature	$G = 1$ (Note 10)	●	2	10	ppm/ $^{\circ}\text{C}$
		$G = 10$ (Note 10)	●	7	20	ppm/ $^{\circ}\text{C}$
V_{CM}	Input Voltage Range	Guaranteed by CMRR $V_S = 3\text{V}, 0\text{V}$, $V_{\text{REF}} = 1.25\text{V}$	●	-5	25	V
		$V_S = 5\text{V}, 0\text{V}$, $V_{\text{REF}} = 1.25\text{V}$	●	-5	80	V
		$V_S = 5\text{V}, 0\text{V}$, $V_{\text{REF}} = 2.5\text{V}$	●	-37	48	V
CMRR	Common Mode Rejection Ratio, RTI	$V_S = 3\text{V}, 0\text{V}$ (Note 7) $V_{\text{CM}} = -5\text{V}$ to 25V , $V_{\text{REF}} = 1.25\text{V}$ LT1990	●	57		dB
		LT1990A	●	67		dB
		$V_S = 5\text{V}, 0\text{V}$ $V_{\text{CM}} = -5\text{V}$ to 80V , $V_{\text{REF}} = 1.25\text{V}$ LT1990	●	57		dB
		LT1990A	●	67		dB
		$V_S = 5\text{V}, 0\text{V}$ (Note 7) $V_{\text{CM}} = -38\text{V}$ to 47V , $V_{\text{REF}} = 2.5\text{V}$ LT1990	●	57		dB
		LT1990A	●	67		dB

3V/5V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$. $V_S = 3\text{V}, 0\text{V}$; $V_S = 5\text{V}, 0\text{V}$; $R_L = 10\text{k}$, $V_{CM} = V_{REF} = \text{half supply}$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990C/LT1990I			UNITS
			MIN	TYP	MAX	
V_{OS}	Input Offset Voltage, RTI	$V_S = 3\text{V}, 0\text{V}$ $G = 1, 10$	●		4.5	mV
		$V_S = 5\text{V}, 0\text{V}$ $G = 1, 10$	●		4.5	mV
$V_{OS/T}$	Input Offset Voltage Drift, RTI	(Note 10)	●	5	22	$\mu\text{V}/^{\circ}\text{C}$
V_{OSH}	Input Offset Voltage Hysteresis, RTI	(Note 11)	●	230		μV
PSRR	Power Supply Rejection Ratio, RTI	$V_S = 2.7\text{V}$ to 12.7V $V_{CM} = V_{REF} = 1.25\text{V}$	●	76		dB
	Minimum Supply Voltage	Guaranteed by PSRR	●		2.7	V
I_S	Supply Current	(Note 8)	●		170	μA
V_{OL}	Output Voltage Swing LOW	$-IN = V^+$, $+IN = \text{Half Supply}$ (Note 8)	●		70	mV
V_{OH}	Output Voltage Swing HIGH	$-IN = 0\text{V}$, $+IN = \text{Half Supply}$ $V_S = 3\text{V}, 0\text{V}$, Below V^+	●		200	mV
		$V_S = 5\text{V}, 0\text{V}$, Below V^+	●		275	mV
I_{SC}	Output Short-Circuit Current	Short to GND (Note 9)	●	2		mA
		Short to V^+ (Note 9)	●	8		mA

3V/5V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$. $V_S = 3\text{V}, 0\text{V}$; $V_S = 5\text{V}, 0\text{V}$; $R_L = 10\text{k}$, $V_{CM} = V_{REF} = \text{half supply}$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990H			UNITS
			MIN	TYP	MAX	
ΔG	Gain Error	$V_{OUT} = 0.5\text{V}$ to $(+V_S) - 0.75\text{V}$ LT1990, $G = 1$	●		0.69	%
		LT1990A, $G = 1$	●		0.37	%
		$G = 10$	●		0.97	%
G/T	Gain vs Temperature	$G = 1$ (Note 10)	●	2	10	ppm/ $^{\circ}\text{C}$
		$G = 10$ (Note 10)	●	7	20	ppm/ $^{\circ}\text{C}$
V_{CM}	Input Voltage Range	Guaranteed by CMRR $V_S = 3\text{V}, 0\text{V}$, $V_{REF} = 1.25\text{V}$	●	-5	25	V
		$V_S = 5\text{V}, 0\text{V}$, $V_{REF} = 1.25\text{V}$	●	-5	80	V
		$V_S = 5\text{V}, 0\text{V}$, $V_{REF} = 2.5\text{V}$	●	-37	48	V
CMRR	Common Mode Rejection Ratio, RTI	$V_S = 3\text{V}, 0\text{V}$ (Note 7) $V_{CM} = -5\text{V}$ to 25V , $V_{REF} = 1.25\text{V}$ LT1990	●	56		dB
		LT1990A	●	66		dB
		$V_S = 5\text{V}, 0\text{V}$ $V_{CM} = -5\text{V}$ to 80V , $V_{REF} = 1.25\text{V}$ LT1990	●	56		dB
		LT1990A	●	66		dB
		$V_S = 5\text{V}, 0\text{V}$ (Note 7) $V_{CM} = -38\text{V}$ to 47V , $V_{REF} = 2.5\text{V}$ LT1990	●	56		dB
		LT1990A	●	66		dB

3V/5V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$. $V_S = 3\text{V}, 0\text{V}$; $V_S = 5\text{V}, 0\text{V}$; $R_L = 10\text{k}$, $V_{CM} = V_{REF} = \text{half supply}$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990H			UNITS
			MIN	TYP	MAX	
V_{OS}	Input Offset Voltage, RTI	$V_S = 3\text{V}, 0\text{V}$ $G = 1, 10$	●		5.2	mV
		$V_S = 5\text{V}, 0\text{V}$ $G = 1, 10$	●		5.2	mV
$V_{OS/T}$	Input Offset Voltage Drift, RTI	(Note 10)	●	5	22	$\mu\text{V}/^{\circ}\text{C}$
V_{OSH}	Input Offset Voltage Hysteresis, RTI	(Note 11)	●	250		μV
PSRR	Power Supply Rejection Ratio, RTI	$V_S = 2.7\text{V}$ to 12.7V $V_{CM} = V_{REF} = 1.25\text{V}$	●	75		dB
	Minimum Supply Voltage	Guaranteed by PSRR	●		2.7	V
I_S	Supply Current	(Note 8)	●		200	μA
V_{OL}	Output Voltage Swing LOW	$-IN = V^+$, $+IN = \text{Half Supply}$ (Note 8)	●		80	mV
V_{OH}	Output Voltage Swing HIGH	$-IN = 0\text{V}$, $+IN = \text{Half Supply}$ $V_S = 3\text{V}, 0\text{V}$, Below V^+	●		230	mV
		$V_S = 5\text{V}, 0\text{V}$, Below V^+	●		275	mV
I_{SC}	Output Short-Circuit Current	Short to GND (Note 9)	●	1		mA
		Short to V^+ (Note 9)	●	5		mA

$\pm 15\text{V}$ ELECTRICAL CHARACTERISTICS

$V_S = \pm 15\text{V}$, $R_L = 10\text{k}$, $V_{CM} = V_{REF} = 0\text{V}$, $G = 1, 10$, $T_A = 25^{\circ}\text{C}$, unless otherwise noted. (Note 6)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
G	Gain	Pins 5 and 8 = Open Pins 5 and 8 = V_{REF}		1 10		
ΔG	Gain Error	$V_{OUT} = \pm 10\text{V}$ LT1990, $G = 1$ LT1990A, $G = 1$ $G = 10$		0.4	0.6	%
				0.07	0.28	%
				0.2	0.8	%
GNL	Gain Nonlinearity	$V_{OUT} = \pm 10\text{V}$ $G = 1$ $G = 10$		0.0008	0.002	%
				0.005	0.02	%
V_{CM}	Input Voltage Range	Guaranteed by CMRR	-250		250	V
CMRR	Common Mode Rejection Ratio, RTI	$V_{CM} = -250\text{V}$ to 250V LT1990 LT1990A	60	68		dB
			70	75		dB
V_{OS}	Offset Voltage, RTI	$G = 1, 10$		0.9	5.2	mV
e_n	Input Noise Voltage, RTI	$f_0 = 0.1\text{Hz}$ to 10Hz		22		μV_{P-P}
	Noise Voltage Density, RTI	$f_0 = 1\text{kHz}$		1		$\mu\text{V}/\sqrt{\text{Hz}}$
R_{IN}	Input Resistance	Differential Common Mode		2		$\text{M}\Omega$
				0.5		$\text{M}\Omega$
PSRR	Power Supply Rejection Ratio, RTI	$V_S = \pm 1.35\text{V}$ to $\pm 18\text{V}$	82	100		dB
	Minimum Supply Voltage	Guaranteed by PSRR		± 1.2	± 1.35	V
I_S	Supply Current			140	180	μA
V_{OUT}	Output Voltage Swing		± 14.5	± 14.79		V

±15V ELECTRICAL CHARACTERISTICS

$V_S = \pm 15V$, $R_L = 10k$, $V_{CM} = V_{REF} = 0V$, $G = 1, 10$, $T_A = 25^\circ C$, unless otherwise noted. (Note 6)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
I_{SC}	Output Short-Circuit Current	Short to V^-	6	9		mA
		Short to V^+	15	22		mA
BW	Bandwidth	$G = 1$		105		kHz
		$G = 10$		7		kHz
SR	Slew Rate	$G = 1$, $V_{OUT} = \pm 10V$	0.3	0.55		V/ μs
	Settling Time to 0.01%	10V Step, $G = 1$		60		μs
AV_{REF}	Reference Gain to Output	$G = 1$		1 ± 0.0007		
		$G = 10$		1 ± 0.007		

The ● denotes the specifications which apply over the temperature range of $0^\circ C \leq T_A \leq 70^\circ C$. $V_S = \pm 15V$, $R_L = 10k$, $V_{CM} = V_{REF} = 0V$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990C/LT1990I			UNITS
			MIN	TYP	MAX	
ΔG	Gain Error	$V_{OUT} = \pm 10V$			0.65	%
		LT1990, $G = 1$	●		0.33	%
		LT1990A, $G = 1$	●		0.9	%
GNL	Gain Nonlinearity	$V_{OUT} = \pm 10V$				
		$G = 1$	●		0.0025	%
		$G = 10$	●		0.025	%
G/T	Gain vs Temperature	$G = 1$ (Note 10)	●	2	10	ppm/ $^\circ C$
		$G = 10$ (Note 10)	●	7	20	ppm/ $^\circ C$
V_{CM}	Input Voltage Range	Guaranteed by CMRR	●	-250	250	V
CMRR	Common Mode Rejection Ratio, RTI	$V_{CM} = -250V$ to 250V				
		LT1990	●	59		dB
		LT1990A	●	68		dB
V_{OS}	Input Offset Voltage, RTI	$G = 1, 10$	●		6.2	mV
V_{OS}/T	Input Offset Voltage Drift, RTI	(Note 10)	●	5	22	$\mu V/^\circ C$
V_{OSH}	Input Offset Voltage Hysteresis, RTI	(Note 11)	●	250		μV
PSRR	Power Supply Rejection Ratio, RTI	$V_S = \pm 1.35V$ to $\pm 18V$	●	80		dB
	Minimum Supply Voltage	Guaranteed by PSRR	●		± 1.35	V
I_S	Supply Current		●		230	μA
V_{OUT}	Output Voltage Swing		●	± 14.4		V
I_{SC}	Output Short-Circuit Current	Short to V^-	●	5		mA
		Short to V^+	●	13		mA
SR	Slew Rate	$G = 1$, $V_{OUT} = \pm 10V$	●	0.25		V/ μs

±15V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$. $V_S = \pm 15\text{V}$, $R_L = 10\text{k}$, $V_{\text{CM}} = V_{\text{REF}} = 0\text{V}$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990C/LT1990I			UNITS
			MIN	TYP	MAX	
ΔG	Gain Error	$V_{\text{OUT}} = \pm 10\text{V}$	●			
		LT1990, $G = 1$	●		0.67	%
		LT1990A, $G = 1$	●		0.35	%
GNL	Gain Nonlinearity	$V_{\text{OUT}} = \pm 10\text{V}$	●			
		$G = 1$	●		0.003	%
		$G = 10$	●		0.03	%
G/T	Gain vs Temperature	$G = 1$ (Note 10)	●	2	10	ppm/°C
		$G = 10$ (Note 10)	●	7	20	ppm/°C
V_{CM}	Input Voltage Range	Guaranteed by CMRR	●	-250	250	V
CMRR	Common Mode Rejection Ratio, RTI	$V_{\text{CM}} = -250\text{V}$ to 250V	●	58		dB
		LT1990 LT1990A	●	67		dB
V_{OS}	Input Offset Voltage, RTI	$G = 1, 10$	●		6.7	mV
V_{OS}/T	Input Offset Voltage Drift, RTI	(Note 10)	●	5	22	μV/°C
V_{OSH}	Input Offset Voltage Hysteresis, RTI	(Note 11)	●	250		μV
PSRR	Power Supply Rejection Ratio, RTI	$V_S = \pm 1.35\text{V}$ to $\pm 18\text{V}$	●	78		dB
		Minimum Supply Voltage	●		±1.35	V
I_S	Supply Current		●		280	μA
V_{OUT}	Output Voltage Swing		●	±14.3		V
I_{SC}	Output Short-Circuit Current	Short to V^-	●	3		mA
		Short to V^+	●	10		mA
SR	Slew Rate	$G = 1, V_{\text{OUT}} = \pm 10\text{V}$	●	0.2		V/μs

±15V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$. $V_S = \pm 15\text{V}$, $R_L = 10\text{k}$, $V_{\text{CM}} = V_{\text{REF}} = 0\text{V}$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS	LT1990H			UNITS
			MIN	TYP	MAX	
ΔG	Gain Error	$V_{\text{OUT}} = \pm 10\text{V}$	●			
		LT1990, $G = 1$	●		0.69	%
		LT1990A, $G = 1$	●		0.37	%
GNL	Gain Nonlinearity	$V_{\text{OUT}} = \pm 10\text{V}$	●			
		$G = 1$	●		0.0035	%
		$G = 10$	●		0.035	%
G/T	Gain vs Temperature	$G = 1$ (Note 10)	●	2	10	ppm/°C
		$G = 10$ (Note 10)	●	7	20	ppm/°C
V_{CM}	Input Voltage Range	Guaranteed by CMRR	●	-250	250	V
CMRR	Common Mode Rejection Ratio, RTI	$V_{\text{CM}} = -250\text{V}$ to 250V	●	57		dB
		LT1990 LT1990A	●	66		dB
V_{OS}	Input Offset Voltage, RTI	$G = 1, 10$	●		7.4	mV
V_{OS}/T	Input Offset Voltage Drift, RTI	(Note 10)	●	5	22	μV/°C

±15V ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range of $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$. $V_S = \pm 15\text{V}$, $R_L = 10\text{k}$, $V_{CM} = V_{REF} = 0\text{V}$, $G = 1, 10$, unless otherwise noted. (Notes 4, 6)

SYMBOL	PARAMETER	CONDITIONS		LT1990H			UNITS
				MIN	TYP	MAX	
V_{OSH}	Input Offset Voltage Hysteresis, RTI	(Note 11)	●		250		μV
PSRR	Power Supply Rejection Ratio, RTI	$V_S = \pm 1.35\text{V}$ to $\pm 18\text{V}$	●	77			dB
	Minimum Supply Voltage	Guaranteed by PSRR	●			± 1.35	V
I_S	Supply Current		●			330	μA
V_{OUT}	Output Voltage Swing		●	± 14.2			V
I_{SC}	Output Short-Circuit Current	Short to V^-	●	1.5			mA
		Short to V^+	●	7			mA
SR	Slew Rate	$G = 1, V_{OUT} = \pm 10\text{V}$	●	0.1			$\text{V}/\mu\text{s}$

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: ESD (Electrostatic Discharge) sensitive device. Extensive use of ESD protection devices are used internal to the LT1990, however, high electrostatic discharge can damage or degrade the device. Use proper ESD handling precautions.

Note 3: A heat sink may be required to keep the junction temperature below absolute maximum.

Note 4: The LT1990C/LT1990I are guaranteed functional over the operating temperature range of -40°C to 85°C . The LT1990H is guaranteed functional over the operating temperature range of -40°C to 125°C .

Note 5: The LT1990C is guaranteed to meet the specified performance from 0°C to 70°C and is designed, characterized and expected to meet specified performance from -40°C to 85°C but is not tested or QA

sampled at these temperatures. The LT1990I is guaranteed to meet specified performance from -40°C to 85°C . The LT1990H is guaranteed to meet specified performance from -40°C to 125°C .

Note 6: $G = 10$ limits are guaranteed by correlation to $G = 1$ tests and gain error tests at $G = 10$.

Note 7: Limits are guaranteed by correlation to -5V to 80V CMRR tests.

Note 8: $V_S = 3\text{V}$ limits are guaranteed by correlation to $V_S = 5\text{V}$ and $V_S = \pm 15\text{V}$ tests.

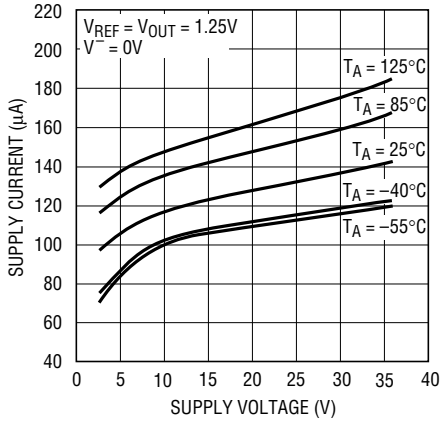
Note 9: $V_S = 5\text{V}$ limits are guaranteed by correlation to $V_S = 3\text{V}$ and $V_S = \pm 15\text{V}$ tests.

Note 10: This parameter is not 100% tested.

Note 11: Hysteresis in offset voltage is created by package stress that differs depending on whether the IC was previously at a higher or lower temperature. Offset voltage hysteresis is always measured at 25°C , but the IC is cycled to 85°C I-grade (70°C C-grade or 125°C H-grade) or -40°C I/H-grade (0°C C-grade) before successive measurement.

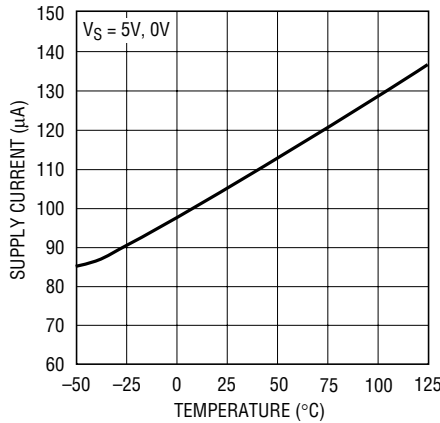
TYPICAL PERFORMANCE CHARACTERISTICS

Supply Current vs Supply Voltage



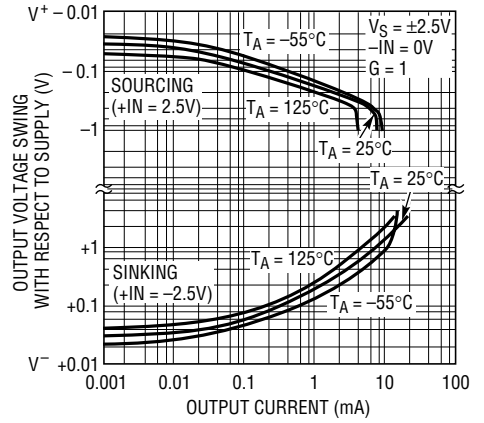
1990 G01

Supply Current vs Temperature



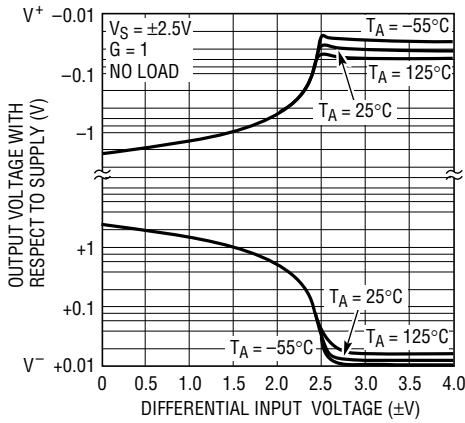
1990 G02

Output Voltage Swing vs Load Current



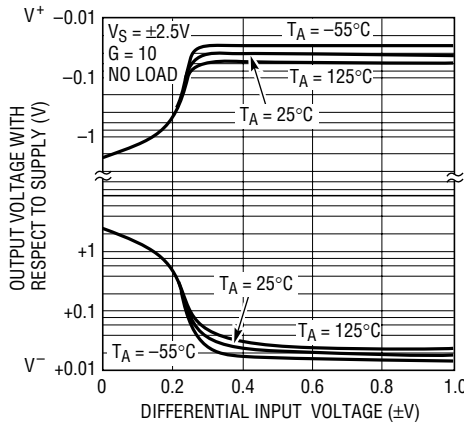
1990 G03

Output Voltage vs Input Voltage, G = 1



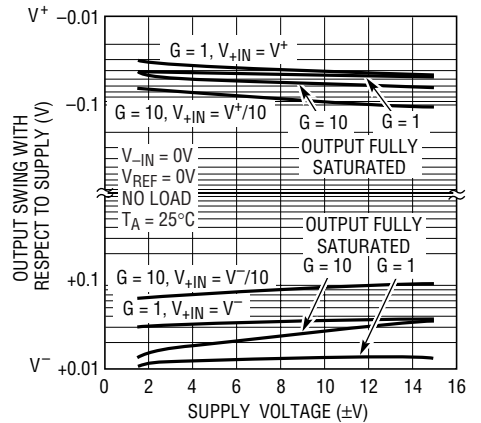
1990 G04

Output Voltage vs Input Voltage, G = 10



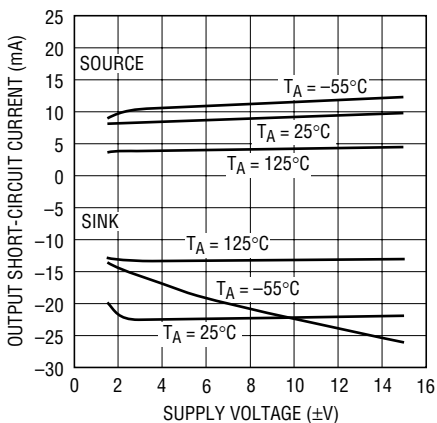
1990 G05

Output Voltage Swing vs Supply Voltage



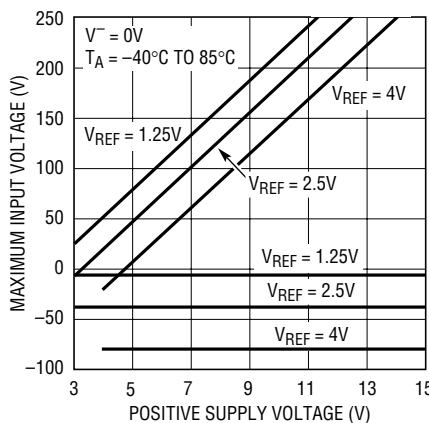
1990 G06

Output Short-Circuit Current vs Supply Voltage



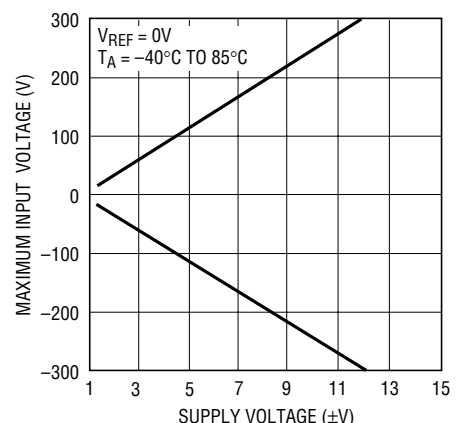
1990 G07

Input Voltage Range vs Single Supply Voltage



1990 G08

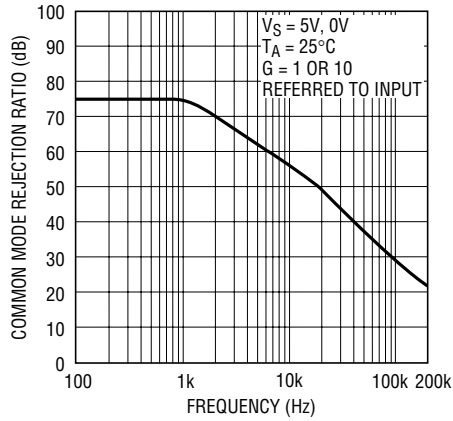
Input Voltage Range vs Split Supply Voltage



1990 G09

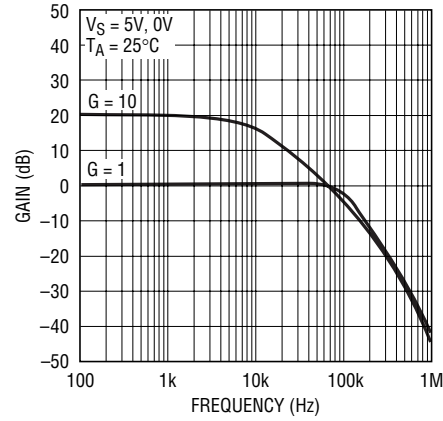
TYPICAL PERFORMANCE CHARACTERISTICS

Common Mode Rejection Ratio vs Frequency



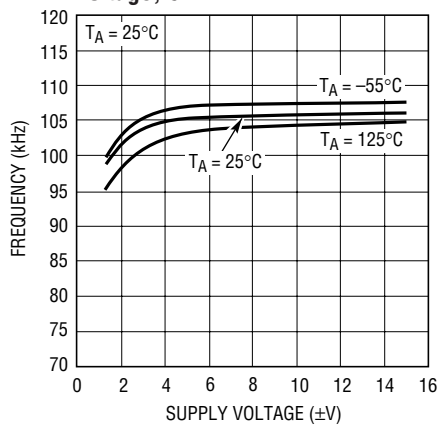
1990 G10

Gain vs Frequency



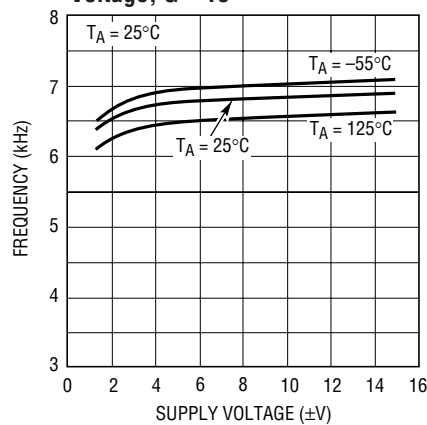
1990 G12

-3dB Bandwidth vs Supply Voltage, $G = 1$



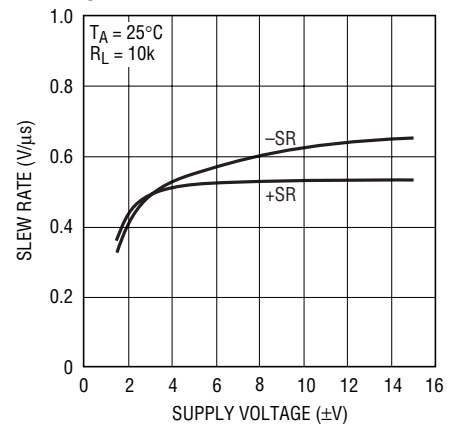
1990 G13

-3dB Bandwidth vs Supply Voltage, $G = 10$



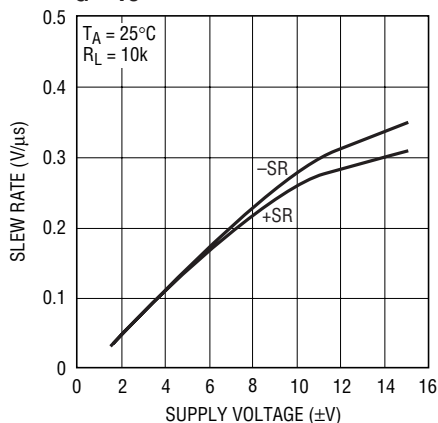
1990 G14

Slew Rate vs Supply Voltage, $G = 1$



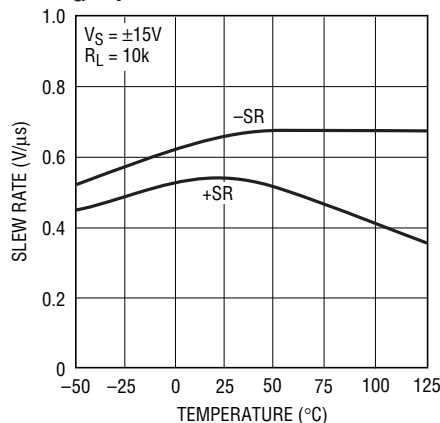
1990 G15

Slew Rate vs Supply Voltage, $G = 10$



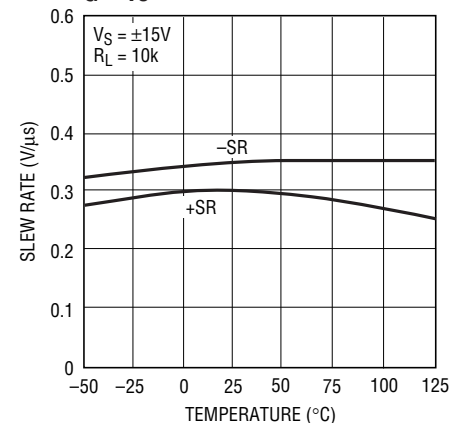
1990 G16

Slew Rate vs Temperature, $G = 1$



1990 G17

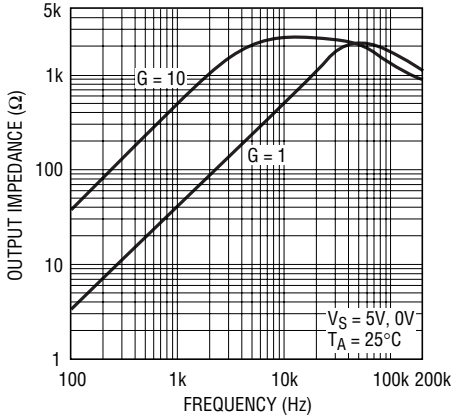
Slew Rate vs Temperature, $G = 10$



1990 G18

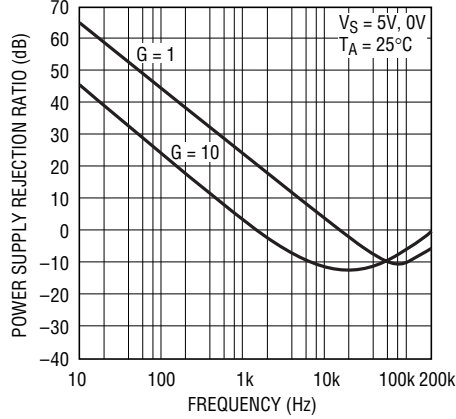
TYPICAL PERFORMANCE CHARACTERISTICS

Output Impedance vs Frequency



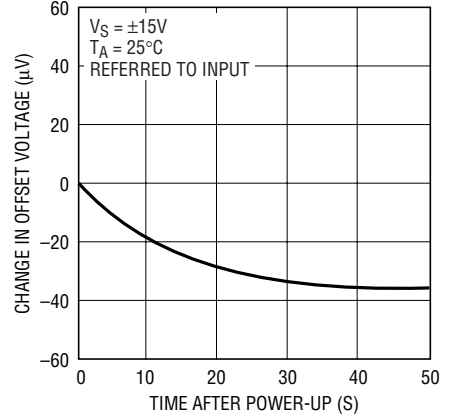
1990 G19

Power Supply Rejection Ratio vs Frequency



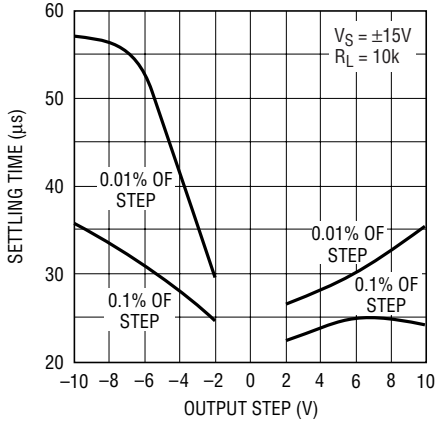
1990 G20

Warm-Up Drift vs Time



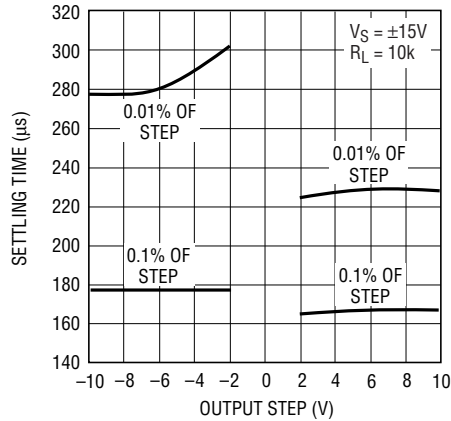
1990 G21

Settling Time vs Output Step, G = 1



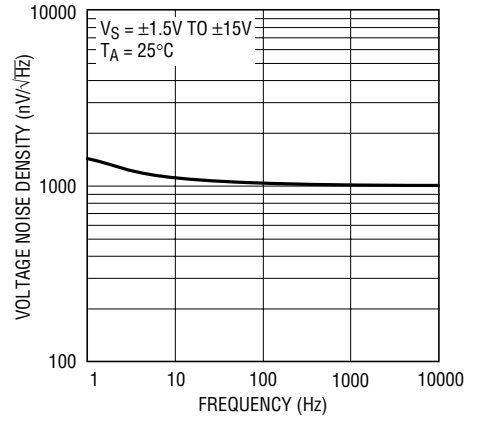
1990 G22

Settling Time vs Output Step, G = 10



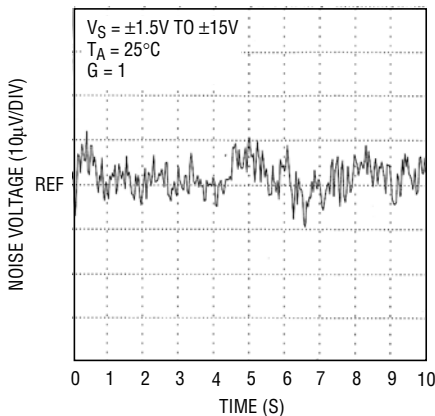
1990 G23

Voltage Noise Density vs Frequency



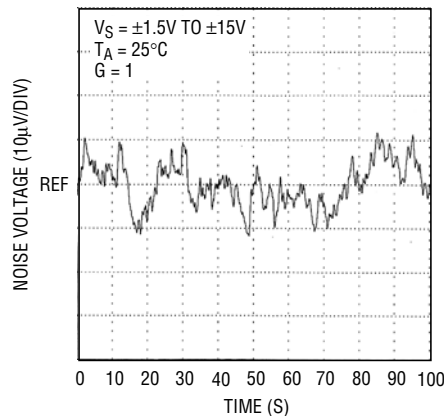
1990 G24

0.1 to 10Hz Noise Voltage



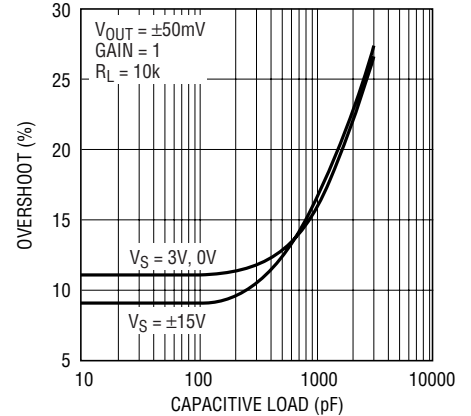
1990 G25

0.01 to 1Hz Noise Voltage



1990 G26

Overshoot vs Capacitive Load



1990 G27

APPLICATIONS INFORMATION

Primary Features

The LT1990 is a complete gain-block solution for high input common mode voltage applications, incorporating a low power precision operational amplifier providing rail-to-rail output swing along with on-chip precision thin-film resistors for high accuracy. The Block Diagram shows the internal architecture of the part. The on-chip resistors form a modified difference amplifier including a reference port for introducing offset or other additive waveforms. With pin-strapping alone either unity gain or gain of 10 is produced with high precision. The resistor network is designed to produce internal common-mode voltage division of 27 so that a very large input range is available compared to the power supply voltage(s) used by the LT1990 itself. The LT1990 is ideally suited to situations where relatively small signals need to be extracted from high voltage circuits, as is the case in many current monitoring instrumentation applications for example. With the ability to accept a range of input voltages well outside the limits of the local power rails and its greater than 1MΩ input impedances, development of precision low power over-the-top and under-the-bottom instrumentation designs is greatly simplified with the LT1990 single chip solution over conventional discrete implementations.

Classic Difference Amplifier

Used in the basic difference amplifier topology where the gain G is pin-strap configurable to be unity or ten, the following relationship is realized:

$$V_O = G \cdot (V_{+IN} - V_{-IN}) + V_{REF}$$

To operate in unity gain, the GAIN1 and GAIN2 pins are left disconnected. For G = 10 operation, the GAIN1 and GAIN2 pins are simply connected to the REF pin.

The input common mode range capability is up to ±250V, governed by the following relationships:

For G = 1 and G = 10 where GAIN1 and GAIN2 are only tied together (not grounded, etc):

$$V_{CM+} \leq 27 \cdot V^+ - 26 \cdot V_{REF} - 23$$

$$V_{CM-} \geq 27 \cdot V^- - 26 \cdot V_{REF} + 27$$

For G = 10 where GAIN1 and GAIN2 are tied to a common potential V_{GAIN} :

$$V_{CM+} \leq 27 \cdot V^+ - 26 \cdot V_{REF} - 23 - V_{GAIN}$$

$$V_{CM-} \geq 27 \cdot V^- - 26 \cdot V_{REF} + 27 - V_{GAIN}$$

For split supplies over about ±11V, the full ±250V common mode range is normally available (with V_{REF} a small fraction of the supply). With lower supply voltages, an appropriate selection of V_{REF} can tailor the input common mode range to a specific requirement. As an example, the following low supply voltage scenarios are readily implemented with the LT1990:

Supply	V_{REF}	V_{CM} Range
+3V	1.25V	-5V to 25V (e.g. 12V automotive environment)
+5V	1.25V	-5V to 80V (e.g. 42V automotive environment)
+5V	4.00V	-77V to 8V (e.g. telecom environment; use downward signaling)

Configuring Other Gains

An intermediate gain G ranging between 1 and 10 may be produced by placing an adjustable resistance between the GAIN1 and GAIN2 pins according to the following nominal relationship:

$$R_{GAIN} \approx (180k/(G - 1)) - 20k$$

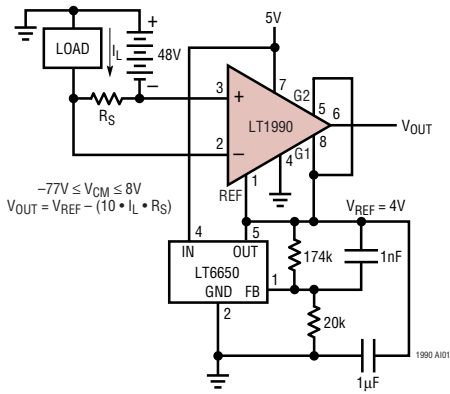
While the expression is exact, the value is approximate because the absolute resistance of the internal network could vary on a unit-to-unit basis by as much as ±30% from the nominal figures and the external gain resistance is required to accommodate that deviation. Once adjusted, however, the gain stability is excellent by virtue of the -30ppm/°C typical temperature coefficient offered by the on-chip thin-film resistor process.

Preserving and Enhancing Common Mode Rejection

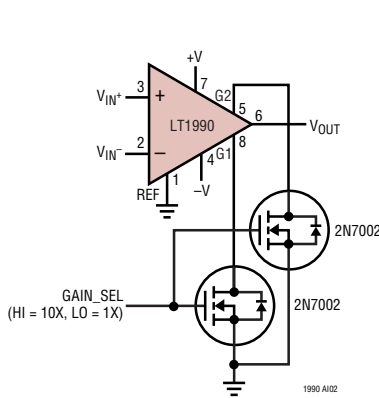
The basic difference amplifier topology of the LT1990 requires that source impedances seen by the input pins +IN and -IN, should be matched to within a few tens of ohms to avoid increasing common mode induced errors beyond the basic production limits of the part. Known source imbalances beyond that level should be compensated for by the addition of series resistance to the lower-impedance source. Also the source impedance of a signal connected to the REF pin must be on the order of a few ohms or less to preserve the high accuracy of the LT1990.

TYPICAL APPLICATION

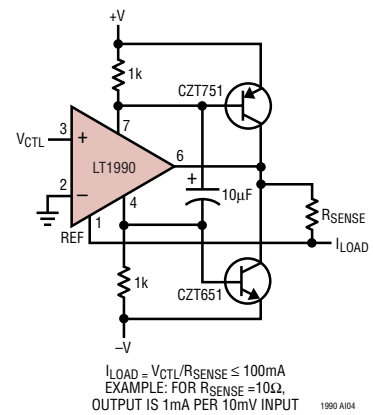
Telecom Supply Current Monitor



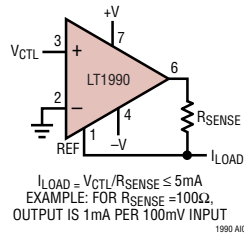
Selectable Gain Amplifier



Boosted Bidirectional Controlled Current Source



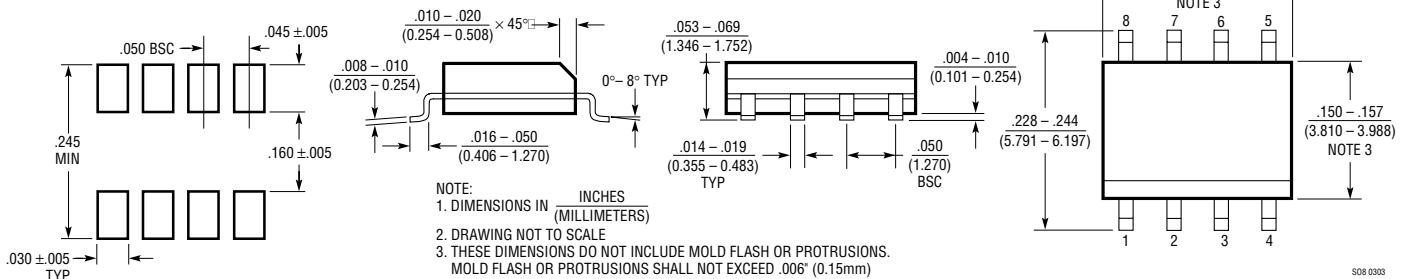
Bidirectional Controlled Current Source



PACKAGE DESCRIPTION

S8 Package
 8-Lead Plastic Small Outline (Narrow .150 Inch)
 (Reference LTC DWG # 05-08-1610)

RECOMMENDED SOLDER PAD LAYOUT



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1787	Precision High Side Current Sense Amplifier	On-Chip Precision Resistor Array
LT1789	Micropower Instrumentation Amplifier	Micropower, Precision, G = 1 to 1000
LTC1921	Dual -48V Supply and Fuse Monitor	Withstands ±200V Transients
LT1991	High Accuracy Difference Amplifier	Micropower, Precision, Pin Selectable G = -13 to 14
LT1995	30MHz, 1000V/μs Gain Selectable Amplifier	Pin Selectable G = -7 to 8
LT6910	Single Supply Programmable Gain Amplifier	Digitally Controlled, SOT-23, G = 0 to 100

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